New Product



SS8P3C, SS8P4C

Vishay General Semiconductor

High Current Density Surface Mount Dual Common-Cathode Schottky Rectifier



K Anode 1 Cathode Anode 2

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 4.0 A				
V _{RRM}	30 V, 40 V				
I _{FSM}	120 A				
E _{AS}	20 mJ				
V_F at $I_F = 4 A$	0.42 V				
T _J max.	150 °C				

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters and polarity protection application.

FEATURES

- Very low profile typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21
 definition

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SS8P3C	SS8P4C	UNIT		
Device marking code		S83C	S84C			
Maximum repetitive peak reverse voltage	V _{RRM}	30	40	V		
Maximum average forward rectified current (fig. 1) total device per diode	I _{F(AV)}	8.0 4.0		А		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	120		A		
Non-repetitive avalanche energy at 25 °C, I_{AS} = 2 A per diode	E _{AS}	20		mJ		
Operating junction and storage temperature range	T _{J,} T _{STG}	- 55 to + 150		°C		





COMPLIANT

Document Number: 89029For tecRevision: 24-Nov-09DiodesAm

For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 2.0 A I _F = 4.0 A	T _A = 25 °C	V _F	0.42 0.48	- 0.58	v
	I _F = 2.0 A I _F = 4.0 A	T _A = 125 °C		0.32 0.42	- 0.48	
Reverse current per diode ⁽²⁾	Rated V _R	T _A = 25 °C T _A = 125 °C	I _R	130 26	300 35	μA mA
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	230	-	pF

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SS8P3C	SS8P4C	UNIT		
Typical thermal resistance per diode	${\sf R}_{ heta JA} {}^{(1)} {\sf R}_{ heta JL}$	60 3		°C/W		

Note

⁽¹⁾ Units mounted on recommended P.C.B. 1 oz. pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS8P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel		
SS8P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel		
SS8P4CHM3/86A (1)	0.10	86A	1500	7" diameter plastic tape and reel		
SS8P4CHM3/87A (1)	0.10	87A	6500	13" diameter plastic tape and reel		

Note

⁽¹⁾ Automotive grade

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RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \degree C \text{ unless otherwise noted})$

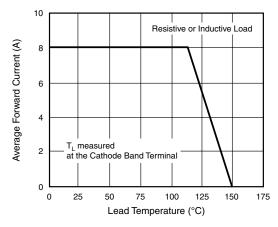


Figure 1. Maximum Forward Current Derating Curve

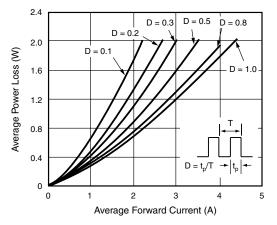
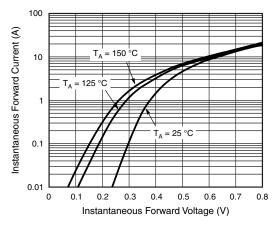


Figure 2. Forward Power Loss Characteristics Per Diode





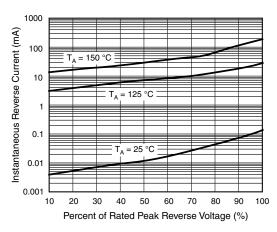


Figure 4. Typical Reverse Leakage Characteristics Per Diode

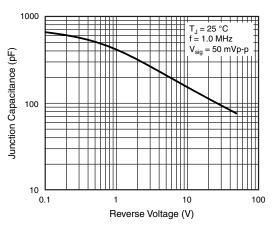
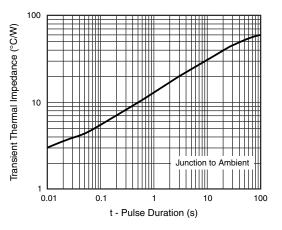
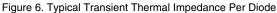


Figure 5. Typical Junction Capacitance Per Diode





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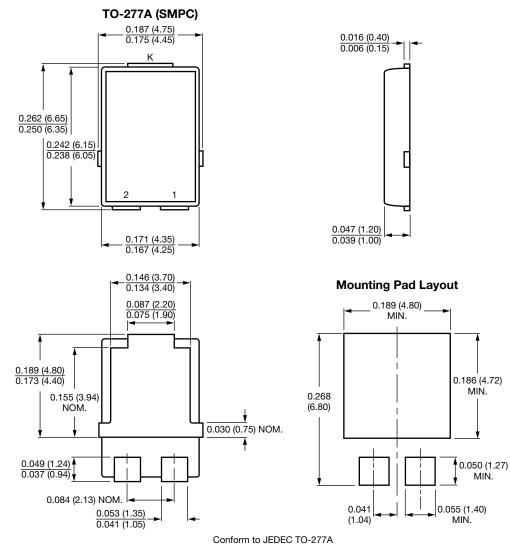
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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